Vishay Semiconductors

High Speed Infrared Emitting Diodes, 850 nm, Surface Emitter Technology



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DESCRIPTION

As part of the SurfLightTM portfolio, the VSMY2853 series are infrared, 850 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

APPLICATIONS

- Miniature light barrier
- Photointerrupters
- · Optical switch
- · Emitter source for proximity sensors
- IR touch panels
- IR illumination

FEATURES

- Package type: surface-mount
- · Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.55
- Peak wavelength: λ_p = 850 nm
- · High reliability
- · High radiant power
- · Very high radiant intensity
- Angle of half intensity: $\varphi = \pm 28^{\circ}$
- · Suitable for high pulse current operation
- · Terminal configurations: gullwing or reverse gullwing
- Package matches with detector VEMD2503X01 series
- Floor life: 4 weeks, MSL 2a, according to J-STD-020
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

PRODUCT SUMMARY				
COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)
VSMY2853RG	50	± 28	850	10
VSMY2853G	50	± 28	850	10

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMY2853RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMY2853G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

Note

MOQ: minimum order guantity



COMPLIANT

HALOGEN FREE

GREEN

(5-2008)



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		١ _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	A	
Power dissipation		Pv	190	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +85	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Soldering temperature	According to Fig. 7, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction-to-ambient	EIA / JESD51	R _{thJA}	250	K/W	

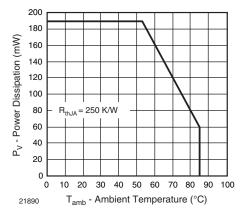


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

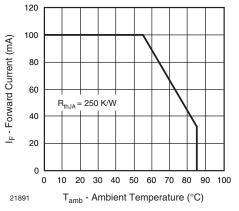


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F	-	1.6	1.9	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F	-	2.8	-	V
Temperature coefficient of V_F	I _F = 100 mA	TK _{VF}	-	-1.5	-	mV/K
Reverse current		I _R	Not designed for reverse operation			μA
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0 mW/cm^{2}$	CJ	-	50	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	27	50	75	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e	-	350	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе	-	55	-	mW
Temperature coefficient of radiant power	I _F = 100 mA	ΤΚφ _e	-	-0.12	-	%/K
Angle of half intensity		φ	-	± 28	-	deg
Peak wavelength	I _F = 100 mA	λ _p	840	850	870	nm
Spectral bandwidth	I _F = 30 mA	Δλ	-	30	-	nm
Temperature coefficient of λ_p	I _F = 30 mA	ΤΚλ _p	-	0.25	-	nm/K
Rise time	I _F = 100 mA, 10 % to 90 %	t _r	-	10	-	ns
Fall time	I _F = 100 mA, 10 % to 90 %	t _f	-	10	-	ns

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BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

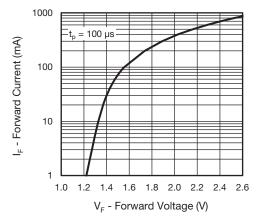


Fig. 3 - Forward Current vs. Forward Voltage

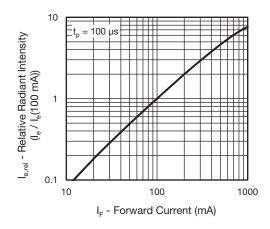
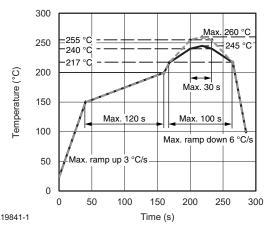
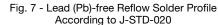


Fig. 4 - Relative Radiant Intensity vs. Forward Current





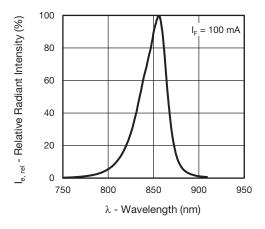


Fig. 5 - Relative Radiant Power vs. Wavelength

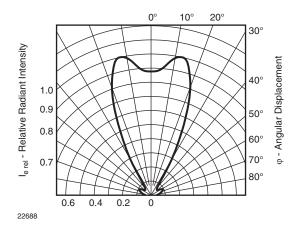


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 2a, according to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

Rev. 1.3, 31-Jul-2018

SOLDER PROFILE

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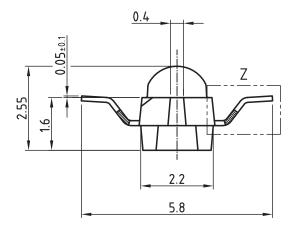


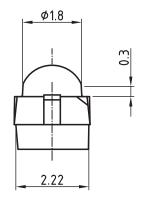


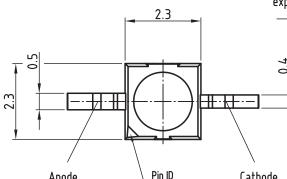
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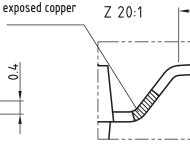
0.8

PACKAGE DIMENSIONS in millimeters: VSMY2853RG





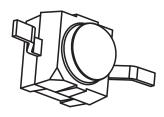


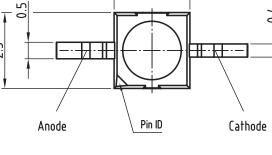


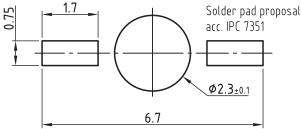


technical drawings according to DIN specifications

Dimensions in mm Not indicated tolerances ±0.2







Drawing refers to following types:

VSMY2853RG

Drawing-No.: 6.544-5409.03-4 Issue: prel. 03.08.12

Document Number: 83480

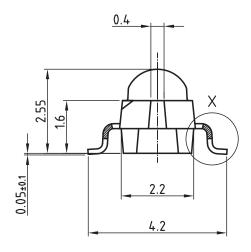
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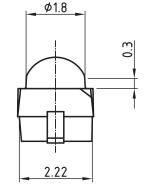
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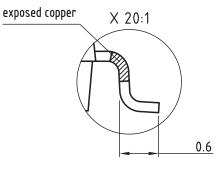


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PACKAGE DIMENSIONS in millimeters: VSMY2853G

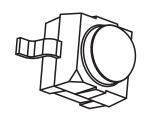


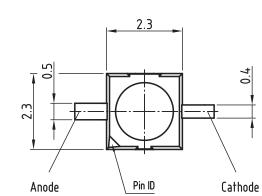


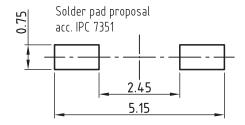




Dimensions in mm Not indicated tolerances ±0.2



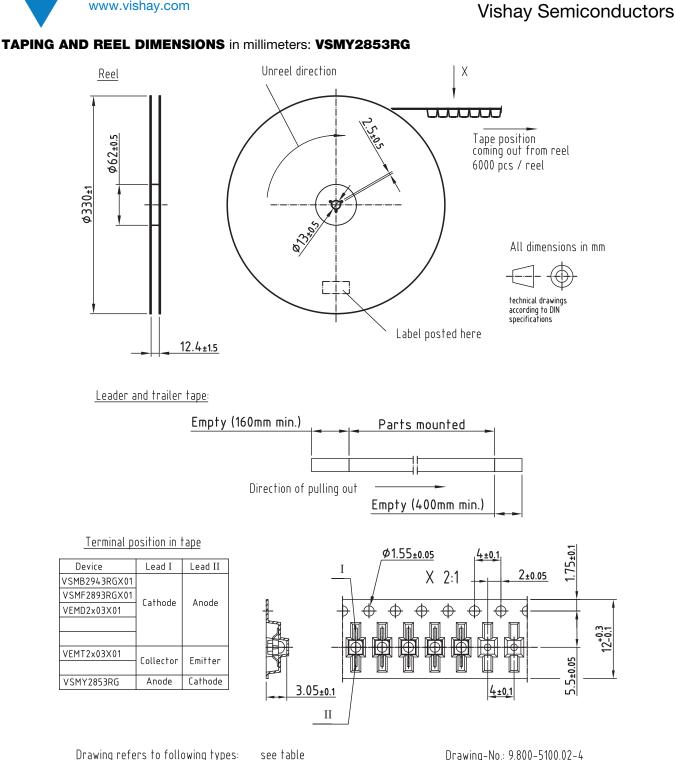




Drawing refers to following types:

VSMY2853G

Drawing-No.: 6.544-5408.03-4 Issue: prel; 03.08.12



Drawing refers to following types: Reel dimensions and tape

Drawing-No.: 9.800-5100.02-4 Issue: prel; 03.08.12

VSMY2853RG, VSMY2853G

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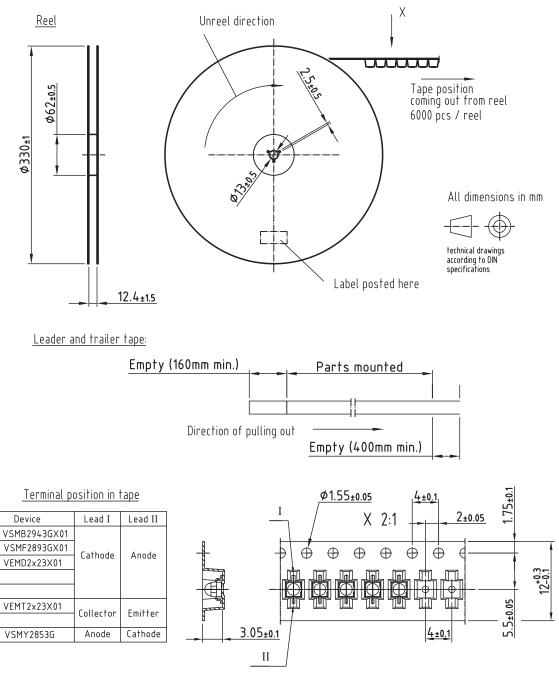
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TAPING AND REEL DIMENSIONS in millimeters: VSMY2853G



Drawing refers to following types: see table Reel dimensions and tape Drawing-No.: 9.800-5091.21-4 Issue: prel; 03.08.12

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